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## TABLE OF CONTENTS

Hafnia-Based Ferroelectric Devices for Lower Power Memory and AI Applications .....	1
<i>Shinichi Takagi, Kasidit Toprasertpong, Eishin Nako, Mitsuru Takenaka, Ryosho Nakane</i>	
Wurtzite-Type Ferroelectrics for Microelectronic Devices: Scalability and Integration to Silicon Based Ferroelectric FETs.....	4
<i>Simon Fichtner, Georg Schönweiger, Frank Dietz, Henning Hanssen, Heiko Züge, Tom-Niklas Kreutzer, Fabian Lofink, Hermann Kohlstedt, Holger Kapels, Michael Mensing</i>	
Tuning Indirect-To-Direct Bandgap of Lonsdaleite Si <sub>0.5</sub> Ge <sub>0.5</sub> Alloy Via Compressive Strain for Optical Gain .....	7
<i>Rishikanta Mayengbam, Subhasis Das, Chuan Seng Tan, Weijun Fan</i>	
Bi <sub>2</sub> O <sub>2</sub> Se-Perovskite Heterostructure Based Bipolar Photosensors as Reconfigurable Logic-In-Sensor Devices .....	10
<i>Lei Xu, Shuo Liu, Ru Huang, Ming He</i>	
A Liquid Medium Coriolis Gyroscope Based on Electrochemical Molecular Electronic Transducer for Low Angular Rate Sensing .....	13
<i>Yik Kin Cheung, Hongyu Yu</i>	
Process Control Challenges and Solutions for Advanced Semiconductor Devices.....	16
<i>Yun Jung Jee, Sang Hyun Han, Shay Wolfing</i>	
Budgeting and Predicting Pattern Defects Using Edge Placement Error and Machine Learning .....	19
<i>Taekwon Jee, Joonsang You, Hong-Goo Lee, Sang-Ho Lee, Seungmo Hong, Jaewook Seo, Roi Meir, Noam Oved, Jun Park, Shin-Ik Kim, Byung-Jo Lim, Chan-Hee Kwak, Jeong-Ho Yeo</i>	
Vector-Matrix-Multiplication Acceleration with Multi-Input Pr <sub>0.7</sub> Ca <sub>0.3</sub> MnO <sub>3</sub> Based RRAM for Highly Parallel In-Memory Computing.....	23
<i>Jayatika Sakhuja, Vivek Saraswat, Sandip Lashkare, Udayan Ganguly</i>	
TaO <sub>x</sub> ReRAM Cell-Level Unidirectional Neural Network Weight Control for Non-Linearity & Variation Robust Transfer Learning of Low Cost Digital eCiM.....	26
<i>Ayumu Yamada, Naoko Misawa, Shunsaku Muraoka, Ken Kawai, Chihiro Matsui, Ken Takeuchi</i>	
Variability Aware FET Model with Physics Knowledge Based Machine Learning .....	29
<i>Kumar Sheelvardhan, Surila Guglani, M. Ehteshamuddin, Sourajeet Roy, Avirup Dasgupta</i>	
Graphical Approach of Equipment Health Monitoring Using Network Analysis .....	32
<i>Wanwook Ki, Minjae Choi, Yongjun Lee, Kiseop Yoon, Hanchan Hwang, Jisoo Park, Taewook Kang, Jaeyong Park, Younghoon Kim</i>	
A Closer Look to Fan-Out Panel Level Packaging.....	35
<i>Tanja Braun, Ole Hölck, Marcus Voitell, Mattis Obst, Steve Voges, Karl-Friedrich Becker, Rolf Aschenbrenner, Martin Schneider-Ramelow</i>	
A Noble VFO(Vertical Wire Fan Out) Technology for Small Form Factor and High Performance Memory Applications .....	38
<i>Ki-Jun Sung, Kyoungtae Eun, Seowon Lee, Sungwon Yoon, Ho-Young Son, Kang-Wook Lee</i>	

Broadband Graphene-Silicon Integrated Imagers.....	42
<i>Yang Xu, Li Chen, Li Peng, Wenzhang Fang, Yance Chen, Xiaocheng Wang, Yunfan Dong, Srikrishna Chanakya Bodepudi, Yuda Zhao, Chao Gao, Bin Yu</i>	
Highly Responsive Ultraviolet Narrowband Organic Photodetector Based on Acceptor Free Photomultiplication: A Smart Approach.....	45
<i>Sampati Rao Sridhar, Medha Joshi Pandey, Brijesh Kumar</i>	
A Five-Transistor Active Pixel Sensor with a Wide Dynamic Range and a High-Speed Pixel Operation.....	48
<i>Tao Ma, Chao Gao, Qian Li, Yihong Qi, Shaozhi Deng, Kai Wang</i>	
On the Dopant, Defect States, and Mobility in W Doped Amorphous In <sub>2</sub> O <sub>3</sub> for BEOL Transistors .....	51
<i>Yaoqiao Hu, Khandker Akif Aabrar, Andrea Palmieri, Matthew Bergschneider, Milan Pešic, Chadwin D. Young, Suman Datta, Kyeongjae Cho</i>	
Ru Stress Assessment by Membrane Wrinkling for Interconnect Applications .....	54
<i>Valeria Founta, Jean-Philippe Soulié, Ingrid De Wolf, Joris Van De Vondel, Johan Swerts, Zsolt Tokei, Christoph Adelman</i>	
Low-Resistance (NH <sub>4</sub> ) <sub>x</sub> WO <sub>3</sub> Nanowire Sensors for Acetone Recognition Operating at Low Voltage with Low Power Consumption.....	57
<i>Yuki Narita, Takahisa Tanaka, Ken Uchida</i>	
Temperature Measurement Method Using FET Type Gas Sensor.....	60
<i>Chayoung Lee, Gyuweon Jung, Wonjun Shin, Yujeong Jeong, Jinwoo Park, Donghee Kim, Jae-Joon Kim, Jong-Ho Lee</i>	
ML-Assisted IC Test Binning with Real-Time Prediction at the Edge.....	63
<i>Tomonori Honda, Thijs Haarhuis, Jeffrey D. David, Henri Hannink, Greg Prewitt, Vishnu Rajan</i>	
An Approach to Represent Time Series by Patterns and Process Dependent Statistics to Present Properties of Signals.....	66
<i>Sunjung Kim, Chulhyun Park, Soohyun Chae, Minkyu Sohn, Changho Lee, Younghoon Kim, Jae-Yong Park</i>	
Flip Chip Joining with Injection Molded Solder Technology.....	70
<i>Takashi Hisada, Toyohiro Aoki</i>	
Low Temperature SiCN as Dielectric for Hybrid Bonding .....	73
<i>Venkat Sunil Kumar Channam, Serena Iacovo, Edward Walsby, Igor Belov, Anne Jourdain, Alfonso Sepulveda, Eric Beyne</i>	
Controllable Conductive Filament Formation in Resistive-RAM Using ZnO Nanoparticles and Its Mechanisms.....	76
<i>Jun-Ho Byun, Woon-San Ko, Ki-Nam Kim, Do-Yeon Lee, Eun-Gi Kim, Eun-A Koo, So-Yeon Kwon, Ga-Won Lee</i>	
Crossbar Arrays Based on “Wall” Phase-Change Memory (PCM) and Ovonic-Threshold Switching (OTS) Selector: A Device Integration Challenge Towards New Computing Paradigms in Embedded Applications.....	79
<i>G. Bourgeois, V. Meli, R. Antonelli, C. Socquet-Clerc, T. Magis, F. Laulagnet, B. Hemard, M. Bernard, L. Fellouh, P. Dezest, J. Krawczyk, S. Dominguez, F. Baudin, J. Garrione, C. Pellissier, J.-A. Dallery, N. Castellani, M.-C. Cyrille, C. Charpin, F. Andrieu, G. Navarro</i>	

Five-Fold Reduction in RESET Energy Consumption by Nitrogen Doping in Phase Change Memory .....	82
<i>Wasi Uddin, Ajay Kumar Agrawal, Paritosh Meihar, Avinash Singh, Tarun Malviya, Rohit Ranjan, Sandip Lashkare, Kumar Priyadarshi, Udayan Ganguly</i>	
DC and Transient Microscopic Simulation of Nanowire NMOSFETs.....	85
<i>Christoph Jungemann, Tobias Rippchen, Maziar Noei, Tobias Linn</i>	
Interpolative Device Models for Hafnia-Based FeFETs.....	88
<i>Imtiaz Hossen, Andreu L. Glasmann, Sina Najmaei, Gina C. Adam</i>	
New Understanding of Screen Radius and Re-Evaluation of Memory Window in Cylindrical Ferroelectric Capacitor for High-Density 1T1C FeRAM.....	91
<i>Minyue Deng, Chang Su, Zhiyuan Fu, Kaifeng Wang, Ru Huang, Qianqian Huang</i>	
Advanced SiC Power Technology and Package .....	94
<i>Byongjin Kim, Alexander Bolotnikov, Helen Jeong, Chandong Kim, Hrishkesh Das, Ganesh Ponram</i>	
Analysis and Mitigation of Interference in a Multi-RADAR Environment .....	97
<i>Elochukwu Onyejebu, Arman Lee, Aigerim Ashimbayeva, Bikash Nakarmi, Ikechi A. Ukaegbu</i>	
Robust Real-Time 4K-UHD Videos Streaming Transmission Through Photonic-Based Terahertz Wireless Communication System.....	100
<i>Xuan-Wei Miao, Po-Cheng Su, Fu-Kai Shih, Pouya Torkaman, Kai-Ming Feng, Shang-Hua Yang</i>	
Design and Optimization of a Double Cladding Octo-Wing Segmented Cladding Fibe Using Response Surface Methodology .....	103
<i>Marzieh Pournoury, Donghyun Kim</i>	
Stochastic Resonance Effects of Floating Gate Technology-Based Leaky Integrate-And-Fire (FG LIF) Neurons in Summing Network.....	106
<i>Akira Goda, Chihiro Matsui, Ken Takeuchi</i>	
Ferroelectric FET Based Signed Synapses of Excitatory and Inhibitory Connection for Stochastic Spiking Neural Network Based Optimizer.....	109
<i>Jin Luo, Tianyi Liu, Zhiyuan Fu, Xinming Wei, Qianqian Huang, Ru Huang</i>	
IGZO Photonic-Synaptic Transistors with Outstanding Linearity by Controlling Oxygen Vacancy for Neuromorphic Computing .....	112
<i>Taewon Seo, Juyoung Yun, Yoonyoung Chung</i>	
Contacts for 2D-Material MOSFETs: Recent Advances and Outstanding Challenges.....	115
<i>Steven J. Koester</i>	
Grain-Size Enlargement of MoS <sub>2</sub> Film by Low-Rate Sputtering with Molybdenum Grid.....	118
<i>Shinya Imai, Ryo Ono, Iriya Muneta, Kuniyuki Kakushima, Tetsuya Tatsumi</i>	
Development of MFMIS Gatestack with Thick Hafnium Zirconium Oxide (HZO) for Nonvolatile Memory Application.....	121
<i>Bohyeon Kang, Jongseo Park, Junghyeon Hwang, Sangho Lee, Hunbeom Shin, Jehyun An, Hyunseo You, Sung-Min Ahn, Sanghun Jeon, Rock-Hyun Baek</i>	

3D NAND Memory Operation of Oxide-Semiconductor Channel FeFETs and the Potential Impact of In-Plane Polarization .....	124
<i>Junxiang Hao, Xiaoran Mei, Takuya Saraya, Toshiro Hiramoto, Masaharu Kobayashi</i>	
Guideline of Device Optimization for Ferroelectric InGaZnO Transistor .....	127
<i>Yu-Hao Chen, I-Ting Wang, Yue-Min Zheng, Tuo-Hung Hou</i>	
Back-End-Of-Line-Compatible Anneal-Free Ferroelectric Field-Effect Transistor .....	130
<i>Shih-Hao Tsai, Zhonghua Li, Ma Mo Mo Ei Phyu, Zihang Fang, Sonu Hooda, Chun-Kuei Chen, Evgeny Zamburg, Aaron Voon-Yew Thean</i>	
High-Endurance ( $>10^{11}$ cycles) and Thermally-Stable Sub-100nm TiO <sub>2</sub> Channel FeFET for Low-Power Memory Centric 3D-LSI Applications .....	133
<i>Taro Shiokawa, Reika Ichihara, Takamasa Hamai, Kiwamu Sakuma, Kota Takahashi, Kazuhiro Matsuo, Masumi Saitoh</i>	
An Improved Robust Infinitely Differentiable Drift Resistance Model for BSIM High Voltage Compact Model .....	136
<i>Anant Singhal, Garima Gill, Girish Pahwa, Chenming Hu, Harshit Agarwal</i>	
A New Back-To-Back Graded AlGa <sub>N</sub> Barrier for Complementary Integration Technique Based on GaN/AlGa <sub>N</sub> /GaN Platform .....	139
<i>Jingui Zhou, Huy-Binh Do, Maria Merlyne De Souza</i>	
Characterization and Modeling of I-V, C-V and Trapping Behavior of SiC Power MOSFETs.....	142
<i>Mohammad Sajid Nazir, Ahtisham Pampori, Yawar Hayat Zarkob, Anirban Kar, Yogesh Singh Chauhan</i>	
Enhance Gate Reliability and Threshold Voltage Stability of p-GaN Gate High-Electron-Mobility Transistors .....	145
<i>Haohao Chen, Junting Chen, Chengcai Wang, Zuoheng Jiang, Mengyuan Hua</i>	
Suppressed Dynamic Avalanche and Enhanced Turn-Off dV/dt Controllability in 3300V Scaled IGBTs .....	148
<i>Xiang Zhou, Munetoshi Fukui, Kiyoshi Takeuchi, Takuya Saraya, Toshiro Hiramoto</i>	
Effects of Oxide Species on the Reduction of Contact Resistivity of Al/Oxide/n-GaN MIS Devices .....	151
<i>Jiro Koba, Junichi Koike</i>	
Pixel Design with Improved Demodulation Contrast for Indirect Time-Of-Flight CMOS Image Sensor .....	154
<i>Jaehyung Jang, Hoon-Moo Choi, Jongchae Kim, Kyungdo Kim, Hoon-Sang Oh, Chang-Rock Song</i>	
Silicon-Based High-Gain Photodetector with a Strong 254-Nm Response for Chemical Oxygen Demand (COD) Monitoring in City Sewage Water.....	157
<i>Xin Jin, Haolin Zhao, Chao Gao, Tao Ma, Zhou Zhou, Xinghui Liu, Wangchang Guo, Kai Wang</i>	
Optimized Metasurface Design for Enhanced Organic Light-Emitting Diodes .....	160
<i>Kyunghnam Kang, Seongmin Im, Changhun Lee, Jungho Kim, Donghyun Kim</i>	
Optimization of Performance Metrics of Charge Trapping Synaptic Device for Neuromorphic Applications.....	163
<i>Md. Hasan Raza Ansari, Nazek El-Atab</i>	

NN Algorithm Aware Alternate Layer Retraining on Computation-In-Memory for Write Variation Compensation of Non-Volatile Memories at Edge AI .....	166
<i>Shinsei Yoshikiyo, Naoko Misawa, Chihiro Matsui, Ken Takeuchi</i>	
Neural Network Quantization is All You Need for Energy Efficient ISP .....	169
<i>Hyunwoo Je, Dongil Ryu, Haechang Lee, Kijeong Kim</i>	
A Comprehensive Simulation Study on Capacitive Memory with Metal-Ferroelectric-Insulator- Semiconductor Structure .....	172
<i>Hongrui Zhang, Chengji Jin, Xiaole Jia, Jiajia Chen, Huan Liu, Yan Liu, Xiao Yu, Genquan Han</i>	
Ferroelectric-Like Behaviors of Mobile-Ionic Field-Effect Transistors with Amorphous Dielectrics .....	175
<i>Huan Liu, Chengji Jin, Jiajia Chen, Xiao Yu, Jing Li, Yue Peng, Ran Cheng, Bing Chen, Yan Liu, Yue Hao, Genquan Han</i>	
Self-Heating and Interface Traps Assisted Early Aging Revelation and Reliability Analysis of Negative Capacitance FinFET .....	178
<i>Rajeewa Kumar Jaisawal, Sunil Rathore, Navneet Gandhi, P. N. Kondekar, Shashank Banchhor, V Bharath Sreenivas, Young Suh Song, Navjeet Bagga</i>	
Ultra-Thin Atomic-Layer-Deposited InGaZnO Thin Film Transistors with Back-End-Of-Line Compatibility .....	181
<i>Jie Zhang, Zhuocheng Zhang, Zehao Lin, Dongqi Zheng, Peide D. Ye</i>	
Flexible Electronics with Two-Dimensional and Layered Chalcogenide Compounds .....	184
<i>Alwin Daus</i>	
Continuous Liquid Metal Printing for Rapid Metal Oxide TFT Integration .....	187
<i>William J. Scheideler, Andrew B. Hamlin, Youxiong Ye, Simon Agnew</i>	
Analysis and Design of Stacked-Nanosheet FeFET Synapse Conductance Response Under Identical Pulse Scheme for Neuromorphic Applications .....	190
<i>Heng Li Lin, Pin Su</i>	
Highly Linear and Symmetric 2T Synaptic Device Composed of IGZO Transistors by Identical Charging and Discharging Characteristics .....	193
<i>Suwon Seong, Seongmin Park, Hyunyoung Cho, Yoonyoung Chung</i>	
Scalable Addressing Circuits for a Surface Code Quantum Computer in Silicon .....	196
<i>Rubaya Absar, Hazem Elgabra, Xuesong Chen, François Sfigakis, Jonathan Baugh, Lan Wei</i>	
Ferroelectric Probabilistic Bits Based on Thermal Noise Induced Randomness for Stochastic Computing .....	199
<i>Sheng Luo, Yihan He, Baofang Cai, Xiao Gong, Gengchiao Liang</i>	
Study on Sub-100-NM-Scale Measurement of Temperature Distribution in Joule-Heated Au Nanosheet Gas Sensors Using Self-Assembled Monolayers as Temperature Probes .....	202
<i>Taro Kato, Takahisa Tanaka, Hiromichi Miyagishi, Jun Terao, Ken Uchida</i>	
Linearity Analysis of FeFET Synaptic Devices Considering Random Phase Distributions .....	205
<i>Yen-Ming Pan, Cheng-Kai Lu, Vita Pi-Ho Hu</i>	
Cryogenic Characterization and Model Extraction of 5nm Technology Node FinFETs .....	208
<i>Shivendra Singh Parihar, Girish Pahwa, Jun Z. Huang, Weike Wang, Kimihiko Imura, Chenming Hu, Yogesh Singh Chauhan</i>	

Novel Trench Type Complementary LIGBTs with Common Double Drift Layers for Simple Process and Improvement in Switching Characteristics.....	211
<i>Zijian Zhang, Qi Tang, Suyang Liu, Masahide Inuishi</i>	
The Study of Dislocation Propagation in Si Wafer During IGBT High Thermal Budget Process .....	214
<i>Jiuyang Yuan, Yoshiji Miyamura, Satoshi Nakano, Wataru Saito, Shin-Ichi Nishizawa</i>	
Characterization of Oxide Interface Charges in Trench Field Stop IGBT.....	217
<i>Zhi Lin Sim, Wei Mien Chin, Yi Xiang Bong, David Goh, Voon Cheng Ngwan</i>	
Solid-State High-Gain Optical Sensors with a Non-Avalanche Approach .....	220
<i>Yihong Qi, Chao Gao, Kai Wang</i>	
All-Inkjet-Printed Organic Thin-Film Transistor and Amplifier for Low-Power High-Gain Wearables .....	223
<i>Chen Jiang</i>	
Thermal Modeling of 2.5D Integrated Package of CMOS Image Sensor and FPGA for Autonomous Driving .....	226
<i>Janak Sharda, Madison Manley, Ankit Kaul, Wantong Li, Muhannad Bakir, Shimeng Yu</i>	
A Solid Electrolyte ZnO Thin Film Transistor for Classification of Spoken Digits Using Reservoir Computing.....	229
<i>Ankit Gaurav, Xiaoyao Song, Sanjeev Kumar Manhas, Partha Pratim Roy, Maria Merlyne De Souza</i>	
Avoiding Plasma Damage: MacEtch Enabled $\beta$ -Ga <sub>2</sub> O <sub>3</sub> FinFETs for On-Resistance Reduction and Hysteresis Elimination.....	232
<i>Hsien-Chih Huang, Zhongjie Ren, A F M Anhar Uddin Bhuiyan, Zixuan Feng, Xixi Luo, Alex Q. Huang, Hongping Zhao, Xiuling Li</i>	
Demonstration of p-type GaN FinFETs on Silicon Substrates with Ultrahigh Current ON/OFF Ratio of 10 <sup>9</sup> and Reduced Interface Trap Density .....	235
<i>Hanghai Du, Zhihong Liu, Tao Zhang, Lu Hao, Guangjie Gao, Weichuan Xing, Jincheng Zhang, Yue Hao</i>	
Effects of Unisolated Top Gate on Performance of Dual-Gate InGaZnO Thin-Film Transistor .....	238
<i>Chao Zhang, Xiaodong Huang</i>	
BEOL Compatible Extremely Scaled Bilayer ITO/IGZO Channel FET with High Mobility 106 cm <sup>2</sup> /V.s.....	241
<i>Sonu Hooda, Manohar Lal, Chen Chun-Kuei, Shih-Hao Tsai, Evgeny Zamburg, Aaron Voon-Yew Thean</i>	
Effects of In/Zn Composition on the Performance of Ultra-Thin Atomic Layer Deposited In <sub>x</sub> Zn <sub>1-x</sub> O Channel Thin-Film Transistors .....	244
<i>Yan-Kui Liang, June-Yang Zheng, Jing-Wei Lin, Yi Miao Hua, Tsung-Te Chou, Chun-Chieh Lu, Huai-Ying Huang, Yu-Ming Lin, Chi-Chung Kei, Edward-Yi Chang, Chun-Hsiung Lin</i>	
A Breathable and Flexible Electronic Skin for Long-Term Electroencephalogram Monitoring .....	247
<i>Tian-Rui Cui, Ying-Fen Zeng, Xiao-Shi Li, Yan-Cong Qiao, Ding Li, He Tian, Yi Yang, Si-Fan Yang, Tian-Ling Ren</i>	
Demonstration of MoS <sub>2</sub> Memtransistor with Poly-Si Source/Drain Featuring Tunable Conductance States and Boosted ION.....	250
<i>K. S. Li, M. K. Huang, Y. H. Wang, Y. C. Tseng, C. J. Su</i>	



Van Der Waals Metal-Semiconductor Contacts for High-Performance Polymer Field-Effect Transistors .....	253
<i>Xilin Lai, Chunyan Zhao, Ru Huang, Ming He</i>	
The Top Electrode Tensile Stress Effect on Ferroelectricity of Hf <sub>0.5</sub> Zr <sub>0.5</sub> O <sub>2</sub> Thin Films .....	256
<i>Runhao Han, Peizhen Hong, Jingwen Hou, Zhang Bao, Wenjuan Xiong, Shuai Yang, Jianfeng Gao, Fei Liu, Zongliang Huo</i>	
Performance Evaluation of AFeRAM Under Low Temperature Operation .....	259
<i>Yi-Chuan Chen, Yu-Chen Chen, Kuo-Yu Hsiang, Min-Hung Lee, Pin Su</i>	
Energy-Efficient Annealing Process of HfO <sub>2</sub> -Based Ferroelectric Capacitor Using UV-LED for Green Manufacturing.....	262
<i>Hiroataka Yamada, Satoru Furue, Takehiko Yokomori, Yuki Itoya, Takuya Saraya, Toshiro Hiramoto, Masaharu Kobayashi</i>	
Atomic-Scale Study on Amorphous ZrO <sub>2</sub> /TaON Interface for Ferroelectric-Like Insulator Films .....	265
<i>Zhi Gong, Jiajia Chen, Chengji Jin, Huan Liu, Yan Liu, Xiao Yu, Genquan Han</i>	
A Study on the Thermal Budget of Ferroelectric TiN/Hf <sub>0.5</sub> Zr <sub>0.5</sub> O <sub>2</sub> /TiN Capacitors for Next-Generation Memory Applications .....	268
<i>Hye Ryeon Park, Jeong Gyu Yoo, Jong Mook Kang, Min Kwan Cho, Taeho Gong, Seongbin Park, Seungbin Lee, Jin-Hyun Kim, Seojun Lee, Rino Choi, Harrison Sejoon Kim, Yong Chan Jung, Jiyoung Kim, Si Joon Kim</i>	
Deep Learning for Semiconductor Materials and Devices Design.....	271
<i>Changwook Jeong, Sanghoon Myung, Byungseon Choi, Jinwoo Kim, Wonik Jang, In Huh, Jae Myung Choe, Young-Gu Kim, Dae Sin Kim</i>	
Optimization of Ge Mole Fraction in Sacrificial Layers for Sub-3-Nm Node Silicon Nanosheet FETs .....	274
<i>Sanguk Lee, Jinsu Jeong, Jun-Sik Yoon, Seunghwan Lee Baek, Junjong Lee, Jaewan Lim, Rock-Hyun Baek</i>	
Investigation of Self-Heating Effect in Forksheet FETs for Sub-3-Nm Node .....	277
<i>Jaewan Lim, Jinsu Jeong, Junjong Lee, Seunghwan Lee, Sanguk Lee, Rock-Hyun Baek</i>	
Process Condition Effects on Saddle Fin Profile and Its Device Performance Below 20nm Advanced DRAM.....	280
<i>Yexiao Yu, Zhongming Liu, Hong Ma</i>	
Process-Induced Uniaxial Strain in Nanosheet-FET Based CMOS Technology – Is it Still Beneficial?.....	283
<i>Ramandeep Kaur, Nihar R. Mohapatra</i>	
Deep Insights into Recessed Gate MOS-HEMT Technology for Power Applications .....	286
<i>B. Mohamad, C. Le Royer, F. Rigaud-Minet, C. Piotrowicz, P. Fernandes Paes Pinto Rocha, C. Leurquin, W. Vandendaele, R. Escoffier, J. Buckley, S. Bécu, J. Biscarrat, R. Gwoziecki</i>	
Vertical GaN Power Devices .....	289
<i>Wenwen Li, Dong Ji</i>	
Effect of Parasitic Leakage Currents Associated with the Regrown Aperture of AlGaIn/GaN Current Aperture Vertical Electron Transistors (CAVETs).....	292
<i>Sara Pouladi, Jae Hyun Ryou</i>	

Fabrication of AlGaIn/GaN MIS-HEMTs with Post-Growth Annealing .....	295
<i>Meihua Liu, Yong Zhang, Guoyong Huang</i>	
A Width-Scalable SPICE Model of GaN-HEMTs for X-Band RF Applications .....	298
<i>Md Hasnain Ansari, Raghvendra Dangi, Ahtisham Pampori, Pragya Kushwaha, Ekta Yadav, Santanu Sinha, Yogesh Singh Chauhan</i>	
A Comprehensive Cryogenic CMOS Variability and Reliability Assessment Using Transistor Arrays .....	301
<i>A. Grill, J. Michl, J. Diaz-Fortuny, A. Beckers, E. Bury, A. Chasin, T. Grasser, M. Waltl, B. Kaczer, K. De Greve</i>	
On the Contribution of Secondary Holes in Hot-Carrier Degradation – a Compact Physics Modeling Perspective .....	304
<i>S. E. Tyaginov, E. Bury, A. Grill, Z. Yu, A. Makarov, A. De Keersgieter, M. I. Vexler, M. Vandemaele, R. Wang, A. Spessot, A. Chasin, B. Kaczer</i>	
Forward Body Bias Technique in DRAM Peripheral Transistor at Cryogenic Temperature for Quantum Computing Applications .....	307
<i>Hyunseo You, Jehyun An, Kihoon Nam, Bohyeon Kang, Jongseo Park, Namhyun Lee, Seonhaeng Lee, Rock-Hyun Baek</i>	
A Study of High Voltage NMOSFET Degradation for NAND HVSW Circuit .....	310
<i>Young Gon Lee, Sang Ho Lee, Sung Kye Park</i>	
A Study on the Flash-Light Sintering Characteristics with Respect to the Pattern Width and Interval of the Inkjet-Printed Copper Nano Ink on the Paper Substrate .....	313
<i>Sungjun Choi, Yong-Rae Jang, Hak-Sung Kim, Caroline Sunyong Lee</i>	
A New Insight into the Saturation Phenomenon in Nanosheet Transistor: A Device Optimization Perspective .....	317
<i>Shashank Banchhor, Navjeet Bagga, Nitanshu Chauhan, Manikandan S, Avirup Dasgupta, S. Dasgupta, Anand Bulusu</i>	
Performance Evaluation of Strain Effectiveness of Sub-5 nm GAA FETs with Compact Modeling Based on Neural Networks .....	320
<i>Ji Hwan Lee, Kihwan Kim, Kyungjin Rim, Soogine Chong, Hyunbo Cho, Saeroonter Oh</i>	
Negative-Thermal-Expansion Gate Electrode to Introduce Tensile Strain into the Channel of MOSFETs for Mobility Enhancement .....	323
<i>Hisashi Kino, Takafumi Fukushima, Tetsu Tanaka</i>	
Demonstration of Ultra-Thin Ferroelectric/Dielectric and Anti-Ferroelectric/Dielectric Bilayers for Future DRAM Cell Capacitors .....	326
<i>Dong Ik Suh, Won-Tae Koo, Youngmo Kim, Ja-Yong Kim, Seung Wook Ryu, Heeyoung Jeon, Ki Vin Im, Gwangyeob Lee, Taeone Youn, Hyeonho Jeong, Seho Lee, Myung-Hee Na, Seon Yong Cha</i>	
A Ferroelectric Differential Bit Cell Based Multiple-Time Programmable Physical Unclonable Function (PUF) for IoT Devices Security .....	329
<i>Paritosh Meihar, Srinu Rowtu, Sandip Lashkare, Udayan Ganguly</i>	
A Novel Pulse-Width-Modulated FeFET-Based Analog Content Addressable Memory with High Area- And Energy-Efficiency .....	332
<i>Weikai Xu, Jin Luo, Qianqian Huang, Ru Huang</i>	

Novel Complementary FeFET- Based Lookup Table and Routing Switch Design and Their Applications in Energy/Area-Efficient FPGA .....	335
<i>Yuan-Yu Huang, Po-Tsang Huang, Po-Yi Lee, Pin Su</i>	
Advanced Compact Modeling for Transistor Aging: Trap-Based Approaches and Mixed-Mode Coupling .....	338
<i>Runsheng Wang, Zixuan Sun, Yu Li, Yongkang Xue, Zirui Wang, Pengpeng Ren, Zhigang Ji, Lining Zhang, Ru Huang</i>	
Integrated Wafer and Die Level Simulation of Back End of Line Chemical Mechanical Polishing Processes .....	341
<i>Ushasree Katakamsetty, Stefan Nikolaev Voykov, Boris Vasilev, Sam Nakagawa, Tamba Tugbawa, Jansen Chee, Aaron Gower-Hall, Brian Lee, Weiyang Zhu, Bifeng Li, Kimiko Ichikawa</i>	
Drain Current Variability in 2-Levels Stacked Nanowire Gate All Around P-Type Field Effect Transistors .....	344
<i>Donghyun Kim, Sylvain Barraud, Gerard Ghibaudo, Christoforos Theodorou, Jae Woo Lee</i>	
Application of Deep Artificial Neural Network to Model Characteristic Fluctuation of Multi-Channel Gate-All-Around Silicon Nanosheet and Nanofin MOSFETs Induced by Random Nanosized Metal Grains .....	347
<i>Sagarika Dash, Yiming Li, Wen-Li Sung</i>	
A Novel 1.2kV Snap-Back Suppressed RC-VIGBT with Small Switching Energy Loss and Simple Fabrication Process.....	350
<i>Suyang Liu, Gai Tsukamoto, Haoming Che, Sichang Zhang, Zijian Zhang, Masahide Inuishi</i>	
Correlation Analysis on Local Capacitance-Voltage Profiles of a SiO <sub>2</sub> /SiC Interface Observed by Time-Resolved Scanning Nonlinear Dielectric Microscopy .....	353
<i>Kohei Yamasue, Yasuo Cho</i>	
Selective Area Carrier Concentration Modulation of Single Crystal $\beta$ -Ga <sub>2</sub> O <sub>3</sub> Film Through High Temperature Oxygen Annealing Process.....	356
<i>Qiming He, Qiuyan Li, Xuanze Zhou, Qi Liu, Weibin Hao, Zhao Han, Guangwei Xu, Xiaojun Wu, Shibing Long</i>	
Piezoelectric Micromachined Ultrasonic Transducers for Consumer Electronics Applications.....	359
<i>Lei Zhao, Yipeng Lu</i>	
Transverse Spurious Mode Free SAW Resonators and Delay Line on GaN/Si with High Quality Factor.....	362
<i>Guofang Yu, Renrong Liang, Haiming Zhao, Jun Fu, Tian-Ling Ren</i>	
High Q-Value Solid Mounted Resonator Based on Aluminum Nitride Film.....	365
<i>Yuanhang Qu, Xiang Chen, Xiyu Gu, Zhiwei Wen, Yao Cai, Yan Liu, Chengliang Sun</i>	
Piezotronic Effect Based ZnO Pressure Sensor with TFT Structures.....	368
<i>Ki-Nam Kim, Woon-San Ko, Jun-Ho Byun, Do-Yeon Lee, Eun-Gi Kim, Eun-A Koo, So-Yeon Kwon, Ga-Won Lee</i>	
Demonstration of a Junctionless Negative Capacitance FinFET-Based Hydrogen Gas Sensor: A Reliability Perspective.....	371
<i>Navneet Gandhi, Rajeeva Kumar Jaisawal, Sunil Rathore, P. N. Kondekar, Shashank Banchhor, Navjeet Bagga</i>	

Electro-Thermal Properties and Self-Heating Effect in Multi-Nanosheet FETs: Junctionless Mode Versus Inversion Mode.....	374
<i>Nitish Kumar, Kanyakumari Ashok Bhinge, Ankur Gupta, Pushpapraj Singh</i>	
Cross-Temperature Reliabilities in TLC 3D NAND Flash Memory: Characterization and Solution.....	377
<i>Yifan Guo, Kenie Xie, Xiaotong Fang, Xuepeng Zhan, Jixuan Wu, Jiezhi Chen</i>	
Building the Path to Ubiquitous Wireless Connectivity, from Materials to Systems .....	380
<i>Luis Andia, Yvan Morandini</i>	
Operation Scheme Optimization for Charge Trap Transistors (CTTs) Based on Fully Depleted Silicon-On-Insulator (FDSOI) Platform .....	383
<i>Wannian Wang, Bing Chen, Jiayi Zhao, Sebastien Loubriat, Guillaume Besnard, Christophe Maleville, Olivier Weber, Ran Cheng</i>	
Variable-Temperature Broadband Noise Characterization of MOSFETs for Cryogenic Electronics: From Room Temperature Down to 3 K.....	386
<i>Kenji Ohmori, Shuhei Amakawa</i>	
Improved Electrical Characteristics of Ge p-MOSFET with Ti-GeO <sub>x</sub> Interfacial Layer by In-Situ Plasma-Enhanced Atomic Layer Deposition .....	389
<i>Hui-Hsuan Li, Yu-Hsien Lin, Tsung-Yen Tu, Chao-Hsin Chien</i>	
SiGe-Based Nanowire HBT for THz Applications.....	392
<i>Soumya Ranjan Panda, Sebastien Fregonese, Anjan Chakravorty, Thomas Zimmer</i>	
1T FDSOI Based LIF Neuron Without Reset Circuitry: A Proposal and Investigation.....	395
<i>V Rajakumari, S R Panda, K P Pradhan</i>	
Laser-Induced Recrystallization of Perovskite Quantum Dots for Flexible/Wearable Light-Emitting Devices .....	398
<i>Ji Eun Kim, Jae Chan Heo, Jung Hwan Park, Han Eol Lee</i>	
Highly Flexible Piezoelectric Pressure Sensor at Extremely High-Temperature Range Using Ultrawide-Bandgap III-N Thin Films .....	401
<i>Nam-In Kim, Miad Yarali, Muhammad Aqib, Jae-Hyun Ryou</i>	
All-Solid-State Thin Film Lithium-Ion Battery with High Ionic Conductivity Material LiNbO <sub>3</sub> as Anode .....	404
<i>Xuechen Hu, Fuhan Cui, Xiaodong Huang</i>	
Impact of RF Frequency Bands on the DC and Large Signal Reliability of a 45nm RFSOI NFET Based Power Amplifier Cell.....	407
<i>Aarti Rathi, P. Srinivasan, Abhisek Dixit</i>	
Reliability Prediction for Automotive 5nm and 7nm Technology Node by Using Machine Learning Based Solution.....	410
<i>Hyung Joo Lee, Dongin Kim, Sanghyun Choi, Seungpyo Hong, Doohwan Kwak, Srividya Jayaram, Seungwon Paek, Minho Kwon, Yeongdo Kim, Hyobe Jung, Ivan Kissiov, Melody Tao, Andres Torres, Nathan Greeneltch, Ho Lee</i>	
Predictable ESD Criteria with Proposed Comparison Diagram Between TLP and HBM ESD for Various Device Technologies and Different Substrates.....	413
<i>Hyekjae Lee, Dong-Sung Kim, Jae-Young Noh, Youngboo Kim, Jisun Park, Hyungsoon Shin</i>	

Phosphosilicate Glass-Based Nanosecond Protonic Programmable Resistors for Analog Deep Learning .....	416
<i>Murat Onen, Ju Li, Bilge Yildiz, Jesús A. Del Alamo</i>	
Strategy for Low Temperature HZO Ferroelectric Capacitors for Back-End of Line Applications .....	419
<i>Jin-Hyun Kim, Minjong Lee, Seojun Lee, Yong Chan Jung, Rino Chor, Hyun Jae Kim, Si Joon Kim, Jiyoung Kim</i>	
Sharp Turn-On Diode by Steep SS “PN-Body Tied SOI FET” for Ultra-Low Power RF Energy Harvesting .....	422
<i>Masayuki Ono, Jiro Ida, Takayuki Mori, Koichiro Ishibashi</i>	
Intercalated Multilayer Graphene / Nickel Hybrid Antenna with Enhanced Inductance Density for Size Reduction.....	425
<i>Keigo Hosokawa, Kenta Matsunaga, Kazuyoshi Ueno</i>	
Design and Demonstration of Cu/ Al <sub>2</sub> O <sub>3</sub> /Cu RRAM with Complementary Resistance Switching Characteristic.....	428
<i>Huanmei Yuan, Yang Char, Shunqi Dai, Cristine Jin Estrada, Yuqing Zhang, Annan Xiong, Hao Bai, Guangyu Du, Songhua Cai, Zhimin Li, Songcen Xu, Mansun Chan</i>	
Efficient P-Doping on Solution-Processed WSe <sub>2</sub> Nano-Flake Thin-Film Transistors for Flexible Electronics.....	431
<i>Taoyu Zou, Yong-Young Noh</i>	
Organic Transistors with Biopolymer Gate Dielectric for Circuit and Photo-Sensing Applications .....	434
<i>Gargi Konwar, Sachin Rahi, Shree Prakash Tiwari</i>	
Fast Missing Source Contact Electrical Method Detection on Low Voltage TrenchFET Technology .....	437
<i>F. Cordiano, D. Sanfilippo, A. Stassi, B. Mazza, R. Perego, G. Di Martino, G. Calvagno, M. Astuto, F. Di Venere, G. Pulvirenti, D. Patti</i>	
Dual-Float-Gate Capacitor for Low-Voltage Multi-Level Nonvolatile Memory with Enhanced Retention .....	442
<i>Haixia Li, Hongxu Liao, Baotong Zhang, Ran Bi, Ru Huang, Ming Li</i>	
Quantitative Analysis of Tunnel Oxide Nitrogen Concentration in 3D NAND Using Low Acceleration Voltage, Low Current and Low Temperature STEM-EELS.....	445
<i>Jun-Young Lee, Woo-Young Jung, Jongkyu Cho, Jangwon Oh, Jonghun Kim, Minki Choi</i>	
Temperature-Induced Instability of Retention Characteristics in 3-D NAND Flash Memory .....	448
<i>Ukju An, Gilsang Yoon, Donghyun Go, Jounghun Park, Donghwi Kim, Jongwoo Kim, Jeong-Soo Lee</i>	
High-Frequency Characterization and Modeling of Low and High Voltage FinFETs for RF SoCs.....	451
<i>Yogesh S. Chauhan, Anirban Kar, Shivendra S. Parihar, Jun Z. Huang, Huilong Zhang, Weike Wang, Kimihiko Imura</i>	
Small-Signal Model of Nanosheet FET for High-Frequency Range: A Design Perspective of Parallel Stacking and Dual-Dielectric Spacer.....	454
<i>Jyoti Patel, Nitya Aggarwal, Navjeet Bagga, S. Dasgupta</i>	
Statistical Analysis of Intrinsic High-Frequency Characteristic Fluctuation of Emerging Silicon Gate-All-Around Nanosheet (NS) MOSFETs at Sub-3-Nm Nodes .....	457
<i>Sekhar Reddy Kola, Yiming Li, Min-Hui Chuang, Kazuhiko Endo, Seiji Samukawa</i>	

Radio Frequency Performance of High Mobility 2D Monolayer Au <sub>2</sub> S-Based Transistors .....	460
<i>Om Maheshwari, Jiang Cao, Youseung Lee, Mathieu Luisier, Tarun Agarwal</i>	
On-Chip Canary Circuit Design for Electronic Interconnects by Utilizing RF Resonance Peak Movement as a Prognostic Factor .....	463
<i>Tae Yeob Kang, Donghwan Seo, Taek-Soo Kim</i>	
Selective Cu Electrodeposition for Through Glass Via (TGV) .....	466
<i>Fan Yang, Qing Wang, Jinhyun Lee, Sanghwa Yoon, Bongyoung Yoo</i>	
Periodic Fine Dimple Lines on the Surface of the Grain-Boundary Free Si Films Grown by Continuous-Wave-Laser Lateral Crystallization.....	470
<i>Nobuo Sasaki, Satoshi Takayama, Rikuto Sasai, Yukiharu Uraoka</i>	
Heteroepitaxial InP Growth on a Si(001) Substrate Using a Ge Buffer Layer in MOCVD .....	473
<i>Keun Wook Shin, Sang-Moon Lee, Kiyoun Lee, Euijoon Yoon</i>	
EUV Lighting by the Cold Cathode C-Beam Irradiation Technique.....	476
<i>Bishwa Chandra Adhikari, Sung Tae Yoo, Kyu Chang Park</i>	
Improvement of MoS <sub>2</sub> Film Quality by Solid-Phase Crystallization from PVD Amorphous MoS <sub>x</sub> Film .....	479
<i>Ryo Ono, Shinya Imai, Takamasa Kawanago, Iriya Muneta, Kuniyuki Kakushima, Kazuo Tsutsui, Tetsuya Tatsumi, Shigetaka Tomiya, Hitoshi Wakabayashi</i>	
Facile and Cost-Effective TFA Doped In <sub>2</sub> O <sub>3</sub> Photodetectors for Deep Ultra Violet Applications.....	482
<i>Prachi Gupta, Satinder K. Sharma</i>	
Automatic Prediction of MOSFETs Threshold Voltage by Machine Learning Algorithms.....	485
<i>Seoyeon Choi, Dong Geun Park, Min Jung Kim, Seain Bang, Jungchun Kim, Seunghee Jin, Ki Seok Huh, Donghyun Kim, Sanghyeok Kim, Inkyu Yoon, Jerome Mitard, Cheol E. Han, Jae Woo Lee</i>	
WSe <sub>2</sub> Field-Effect Transistor with Electron-Beam-Induced W-Shaped IV Characteristic and Its Application to a Ternary NAND Gate .....	488
<i>Maksim Andreev, Juncheol Kang, Taeran Lee, Jin-Hong Park</i>	
Novel SCR Device for ESD Protection with High-Holding Voltage in 0.18 $\mu$ m BCD Process .....	491
<i>Myoung Chul Lim, Young Bum Eom, Joung Cheul Choi, Sang Wook Nam, Jeong Soo Park</i>	
Vanadium Dioxide Series and Shunt RF Switches Synthesized Using Low Thermal Budget Process .....	494
<i>Abhishek Mishra, Ashok P, Yogesh Singh Chauhan, Amit Verma</i>	
Biocompatible Memristive Devices for Brain-Inspired Applications.....	497
<i>Aoze Han, Miaocheng Zhang, Liwei Zhang, Xingyu Chen, Yi Tong</i>	
Enhancement in Bipolar Conductance Linearity by One Transistor - One Resistor (1T1R) Cell with Non-Filamentary PCMO-RRAM as Synapse for Neural Networks.....	500
<i>Jayatika Sakhuja, Shubham Patil, Sandip Mondal, Sandip Lashkare, Udayan Ganguly</i>	
Simulation of a Recessed Channel Ferroelectric-Gate Field-Effect Transistor with a Dual Ferroelectric Gate Stack for Memory Application .....	503
<i>Simin Chen, Dae-Hwan Ahn, Seong Ui An, Younghyun Kim</i>	
Performance Improvement of ZnO Based ReRAM with SiCN Oxygen Reservoir.....	506
<i>Woon-San Ko, Myeong Ho Song, Ki-Nam Kim, Jun-Ho Byun, Do-Yeon Lee, Eun-Gi Kim, Eun- A Koo, So-Yeon Kwon, Geun-Ho Kim, Dong-Hyeuk Choi, Ga-Won Lee</i>	

Stability and Performance Optimization of 6T SRAM Cell at Cryogenic Temperature.....	509
<i>Shao-Fu Fang, Vita Pi-Ho Hu</i>	
Variation-Tolerant Ferroelectric FET-Based Ternary Content-Addressable Memories (TCAM) Cell for Meta-Learning Application.....	512
<i>Han-Fu Chuang, Vita Pi-Ho Hu</i>	
MoS <sub>2</sub> - Based 3D Stackable Charge-Trap Memory with AlN Interface Layer for Reducing Optical Phonon Scattering.....	515
<i>Sanggeun Bae, Jungyeop Oh, Mingu Kang, Sung-Yool Choi</i>	
Albumen Based Flexible Memory Device for Bio-Sustainable Electronics.....	518
<i>Anurag Dwivedi, Anil Lodhi, Shalu Saini, Harshit Agarwal, Shree Prakash Tiwari</i>	
Relaxation of Conductance During DC Voltage Pulse off Time in TiN/Hf/HfO <sub>x</sub> /Au/ HfO <sub>x</sub> / TiN – device .....	521
<i>C. Y. Huang, M. Tanaka, T. Shimizu, T. Ito, S. Shingubara</i>	
Flexible Forming Free Resistive Memory Device with 2D Material MoSe <sub>2</sub> as Switching Layer.....	524
<i>Shalu Saini, Anurag Dwivedi, Anil Lodhi, Arpit Khandelwal, Shree Prakash Tiwari</i>	
1D Thermophotovoltaic Emitter: Performance Comparison in N <sub>2</sub> Ambient and Air .....	527
<i>Minsu Oh, Kevin Grossklaus, Thomas E. Vandervelde</i>	
Design of the Drift Layer of 0.6 – 1.7 kV Power Silicon Carbide MOSFETs for Enhanced Short Circuit Withstand Time.....	530
<i>Prashant Singh, Akshay K, Hema Lata Rao Maddi, Anant Agarwal, Shreepad Karmalkar</i>	
Computer Simulation and Performance Optimization of Metal-Semiconductor-Metal Back-Contact Perovskite Solar Cells.....	533
<i>Iliyas T. Dossayev, Assylan Akhanuly, Erik O. Shalenov, Askhat N. Jumabekov</i>	
GA Assisted ANN Based GaN HEMT Model Development and Demonstration of Its CAD Incorporation for Class-F Power Amplifier.....	536
<i>Saddam Husain, Galymzhan Naurzybayev, Mohammad Hashmi</i>	
Effect of the SnO <sub>2</sub> Electron Transport Layer on the Performance of Perovskite Solar Cells .....	539
<i>Assylan Akhanuly, Iliyas T. Dossayev, Erik O. Shalenov, Constantinos Valagiannopoulos, Karlygash N. Dzhumagulova, Annie Ng, Askhat N. Jumabekov</i>	
Analysis and Modeling of OFF-State Capacitance in LDD MOSFETs .....	542
<i>Ayushi Sharma, Ravi Goel, Yogesh Singh Chauhan</i>	
Novel Harmonic Distortion Analysis Method Using Ramo-Shockley Theorem.....	545
<i>Nak Won Yu, Jong Min Kim, Young Chul Kim, Hyunchul Nah</i>	
A Statistical Assessment of Zener Diode Behavior Using Functional Data Analysis.....	549
<i>Xiaoxia Champon, David Angeles, Thomas Buchheit, David Canfield, J. Derek Tucker, Jason Adams</i>	
Mean Estimation and Nominal Device Selection with the Pairwise Midpoint Method .....	552
<i>Jason Adams, Thomas Buchheit, Abdullah Al Mamun Mazumder, Biazid Kabir Moghal, Md Fazle Rabbe, Ahsanul Islam, Shahed Reza</i>	
A Study of the non-Weibull Distribution of HK PMOS TDDDB .....	555
<i>Jeong-Hwan Hwang, Yong Gon Lee, Sang Ho Lee, Sung Kye Park</i>	

Different Proposed Analysis with TCAD for Catastrophic Large Area Failure Due to Radiation Stress on 4H-SiC Schottky Diode .....	558
<i>Hyeokjae Lee, Ji-Min Park, Dongwoo Bae, Kiseok Kim, Jae-Young Noh, Youngboo Kim, Jisun Park, Hyungsoon Shin</i>	
Gr-Gb Channel Difference Improvement of CMOS Image Sensor with Transfer Gate Barrier Optimization.....	561
<i>Youngju Lee, Namyoon Kim, Hyosik Kim, Wonho Lee</i>	
Improvement of RTS Noise and Peel off Issue of BSI CIS Products by Changing FEP Film Stack Raw Material .....	564
<i>So-Yun Kim, Joohee Kim, Heejeong Hong, Youngju Lee, Wonho Lee</i>	
A Flexible Neural Probe with Electrodeposited Silk Composite as an Insertion Shuttle .....	567
<i>Mi Kyung Kim, Jia Chee Leong, Hyunjoo J. Lee</i>	
CMUT Humidity Sensor with a Calcium-Modified Silk Functionalized Layer.....	570
<i>Taemin Lee, Sang-Mok Lee, Hyunjoo Jenny Lee</i>	
Development of a Smart Glove with Robust Bending Sensing Units for Advanced Human-Machine Interfacing .....	573
<i>Yue Hou, Hongming Cao, Yang Li, Zhaoyu Li, Qian Wang, Ziyu Wang, Hongyu Yu</i>	
Experimental Results of Adjusting Membrane Stress and Sacrificial Layer Thickness for Targeting the Pull-In Voltage of Capacitive MEMS Microphone Structure .....	576
<i>Ju Chan Choi, Young Chan Choi, Seok Jo Chang, Kwan Soo Kim, Tae Won Lee, Jae Hee Lee</i>	
Printed Flexible Quasi-Interdigitated Back-Contact Perovskite Solar Cells .....	579
<i>Hryhorii P. Parkhomenko, Askhat N. Jumabekov</i>	
Mechanochemical Synthesis of Zero-Dimensional Metal Halide Perovskites.....	582
<i>Yongjin Kim, Kyeong-Yoon Baek, Hyeonmin Choi, Joonha Jung, Takhee Lee, Keehoon Kang</i>	
Strategies for Improving the Device Performance of 2D Perovskite Field-Effect Transistors .....	585
<i>Hyeonmin Choi, Seok Woo Lee, Joonha Jung, Yeeun Kim, Jaeyong Woo, Youjin Reo, Yong-Young Noh, Takhee Lee, Keehoon Kang</i>	
Unveiling Root Cause of Defect Assisted Filamentation and Implication on Resistive Switching in MoS <sub>2</sub> Atomristor.....	588
<i>Asif A. Shah, Jeevesh Kumar, Aadil Bashir Dar, Mayank Shrivastava</i>	
Schottky Barrier MOSFET Enabled Ultra-Low Power Real-Time Neuron for Neuromorphic Computing.....	591
<i>Shubham Patil, Jayatika Sakhuja, Ajay Kumar Singh, Anmol Biswas, Vivek Saraswat, Sandeep Kumar, Sandip Lashkare, Udayan Ganguly</i>	
System-Level Performance of MoS <sub>2</sub> Synaptic Transistors in MLP and DNN Architectures .....	594
<i>Aaseesh Rallapalli, Shubhadeep Bhattacharjee</i>	
High-Speed 405nm Violet Superluminescent Diode for 3.6 Gbps Visible Light Communication.....	597
<i>Mengxi Dong, Junfei Wang, Chicheng Ma, Dong Li, Shanshan Wang, Lulu Zha, Nan Chi, Chao Shen</i>	
Enhanced Efficiency Roll-Off Characteristics in Quantum Dot Light-Emitting Diodes by Engineering Interface of Bilayer Electron Transport Layers.....	600
<i>Kyoungeun Lee, Jaeyeop Lee, Jaehoon Kim, Jeongkyun Roh</i>	



Photonicallly Generated Waveforms Based on Single and Double Injection in a Semiconductor Laser for RADAR Applications .....	604
<i>Anuar Turekhanov, Suanu Nwigbo, Arman Lee, Bikash Nakarmi, Ikechi A. Ukaegbu</i>	
Improved Performance of InP-Based Quantum Dot Light-Emitting Diodes by Employing a Cascading Hole Injection/Transport Layer.....	607
<i>Yeyun Bae, Jaeyeop Lee, Jeongkyun Roh</i>	
Performance Variation with Changes in Ultrathin Ge Film Thickness of Self-Aligned Double-Gate Cu-MIC Low-Temperature Poly-Ge TFTs on Glass Substrates .....	610
<i>Sho Suzuki, Akito Hara</i>	
A Multiple Junction Photonic Demodulator with Low Power Consumption for Time-Of-Flight Application .....	613
<i>Shun-Qi Dai, Cristine Jin Estrada, Annan Xiong, Huanmei Yuan, Songcen Xu, Chen Xu, Jie George Yuan, Mansun Chan</i>	

**Author Index**